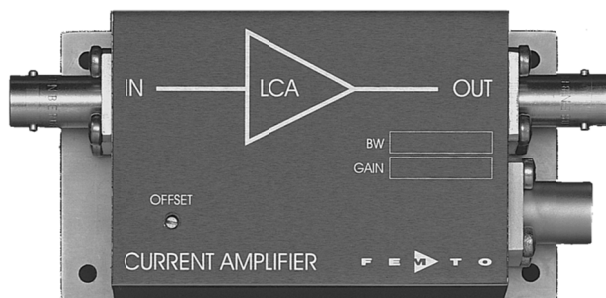
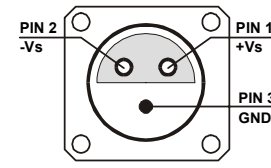


## Ultra-Low-Noise Current Amplifier



<p>Features</p>	<ul style="list-style-type: none"> <li>• <b>Bandwidth and Frequency Response Independent of Detector-Capacitance (up to 10 nF)</b></li> <li>• <b>Extremely Low Noise, 1.5 fA/√Hz Equivalent Input Noise Current</b></li> <li>• <b>Bandwidth DC ... 200 Hz</b></li> <li>• <b>Transimpedance (Gain) 1 x 10<sup>10</sup> V/A</b></li> </ul>																									
<p>Applications</p>	<ul style="list-style-type: none"> <li>• <b>Photodiode- and Photomultiplier-Amplifier</b></li> <li>• <b>Spectroscopy</b></li> <li>• <b>Charge-Amplifier</b></li> <li>• <b>Ionisation Detectors</b></li> <li>• <b>Preamplifier for Lock-Ins, A/D-Converters, etc.</b></li> </ul>																									
<p>Specifications</p>	<table border="0"> <tr> <td colspan="2" data-bbox="563 1025 703 1055"><i>Test Conditions</i></td> <td data-bbox="879 1025 1374 1084"><i>V<sub>s</sub> = ± 15 V, T<sub>a</sub> = 25°C Warm-up 20 minutes (min. 10 minutes recommended)</i></td> </tr> <tr> <td data-bbox="276 1111 320 1140">Gain</td> <td data-bbox="563 1111 711 1169">Transimpedance Accuracy</td> <td data-bbox="879 1111 1126 1169">1 x 10<sup>10</sup> V/A (&gt;10 kΩ Load) ± 1%</td> </tr> <tr> <td data-bbox="276 1200 464 1229">Frequency Response</td> <td data-bbox="563 1200 791 1312">Lower Cut-Off Frequency Upper Cut-Off Frequency Rise- / Fall-Time Gain Flatness</td> <td data-bbox="879 1200 1046 1312">DC 200 Hz (- 3 dB) 2 ms (10% - 90%) ± 0.1 dB</td> </tr> <tr> <td data-bbox="276 1344 320 1373">Input</td> <td data-bbox="563 1344 823 1581">Equ. Input Noise Current Equ. Input Noise Voltage Input Bias Current Input Bias Current Drift Offset Current Compensation Max. Input Current Input Offset Voltage DC Input Impedance</td> <td data-bbox="879 1344 1238 1581">1.5 fA/√Hz (@ 10 Hz) 90 nV/√Hz (@ 10 Hz) 20 fA typ. / 30 fA max. Factor 2 / 10 K ± 300 pA, Adjustable by Offset-Trimpot ± 1 nA (Linear Amplification) &lt; 0.5 mV 1 kΩ (Virtual) // 5 pF</td> </tr> <tr> <td data-bbox="276 1612 336 1641">Output</td> <td data-bbox="563 1612 743 1702">Output Voltage Output Impedance Max. Output Current</td> <td data-bbox="879 1612 1358 1702">± 10 V (&gt;10 kΩ Load) 50 Ω (Terminate with &gt;10 kΩ for best Performance) ± 10 mA (Linear Amplification)</td> </tr> <tr> <td data-bbox="276 1733 400 1762">Power Supply</td> <td data-bbox="563 1733 695 1792">Supply Voltage Supply Current</td> <td data-bbox="879 1733 999 1792">± 15 V ± 15 mA typ.</td> </tr> <tr> <td data-bbox="276 1823 320 1852">Case</td> <td data-bbox="563 1823 632 1872">Weight Material</td> <td data-bbox="879 1823 1110 1872">210 gr. (0.5 lbs) AlMg4.5Mn, nickel-plated</td> </tr> <tr> <td data-bbox="276 1904 456 1933">Temperature Range</td> <td data-bbox="563 1904 775 1962">Storage Temperature Operating Temperature</td> <td data-bbox="879 1904 1023 1962">-40 ... +100 °C 0 ... +60 °C</td> </tr> </table>		<i>Test Conditions</i>		<i>V<sub>s</sub> = ± 15 V, T<sub>a</sub> = 25°C Warm-up 20 minutes (min. 10 minutes recommended)</i>	Gain	Transimpedance Accuracy	1 x 10 <sup>10</sup> V/A (>10 kΩ Load) ± 1%	Frequency Response	Lower Cut-Off Frequency Upper Cut-Off Frequency Rise- / Fall-Time Gain Flatness	DC 200 Hz (- 3 dB) 2 ms (10% - 90%) ± 0.1 dB	Input	Equ. Input Noise Current Equ. Input Noise Voltage Input Bias Current Input Bias Current Drift Offset Current Compensation Max. Input Current Input Offset Voltage DC Input Impedance	1.5 fA/√Hz (@ 10 Hz) 90 nV/√Hz (@ 10 Hz) 20 fA typ. / 30 fA max. Factor 2 / 10 K ± 300 pA, Adjustable by Offset-Trimpot ± 1 nA (Linear Amplification) < 0.5 mV 1 kΩ (Virtual) // 5 pF	Output	Output Voltage Output Impedance Max. Output Current	± 10 V (>10 kΩ Load) 50 Ω (Terminate with >10 kΩ for best Performance) ± 10 mA (Linear Amplification)	Power Supply	Supply Voltage Supply Current	± 15 V ± 15 mA typ.	Case	Weight Material	210 gr. (0.5 lbs) AlMg4.5Mn, nickel-plated	Temperature Range	Storage Temperature Operating Temperature	-40 ... +100 °C 0 ... +60 °C
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## Ultra-Low-Noise Current Amplifier

Absolute Maximum Ratings	Input Voltage	± 10 V
	Power Supply Voltage	± 22 V
Connectors	Input	BNC
	Output	BNC
	Power Supply	LEMO Series 1S, 3-pin Fixed Socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND
		

Application Diagrams

Photo Detector Biasing in Photovoltaic Mode:  
Use for Low Speed Applications and Minimum Dark Current.

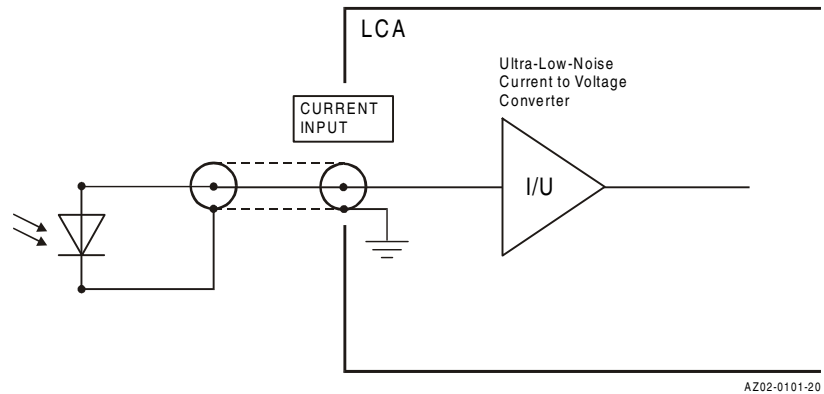
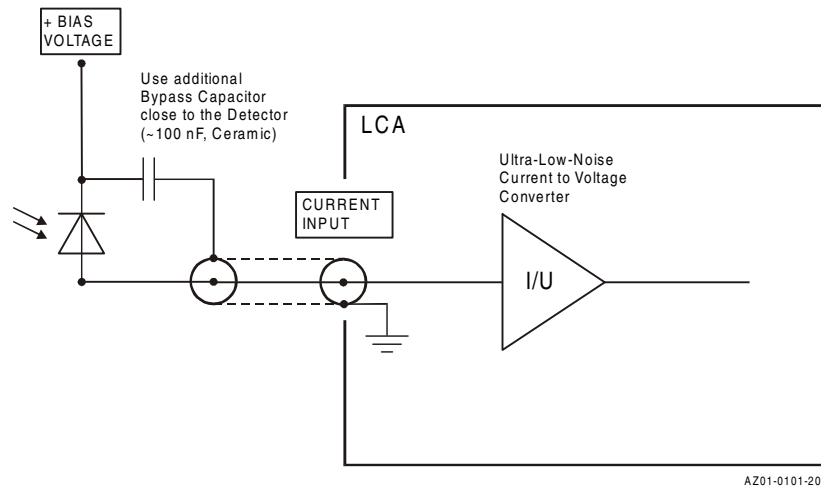
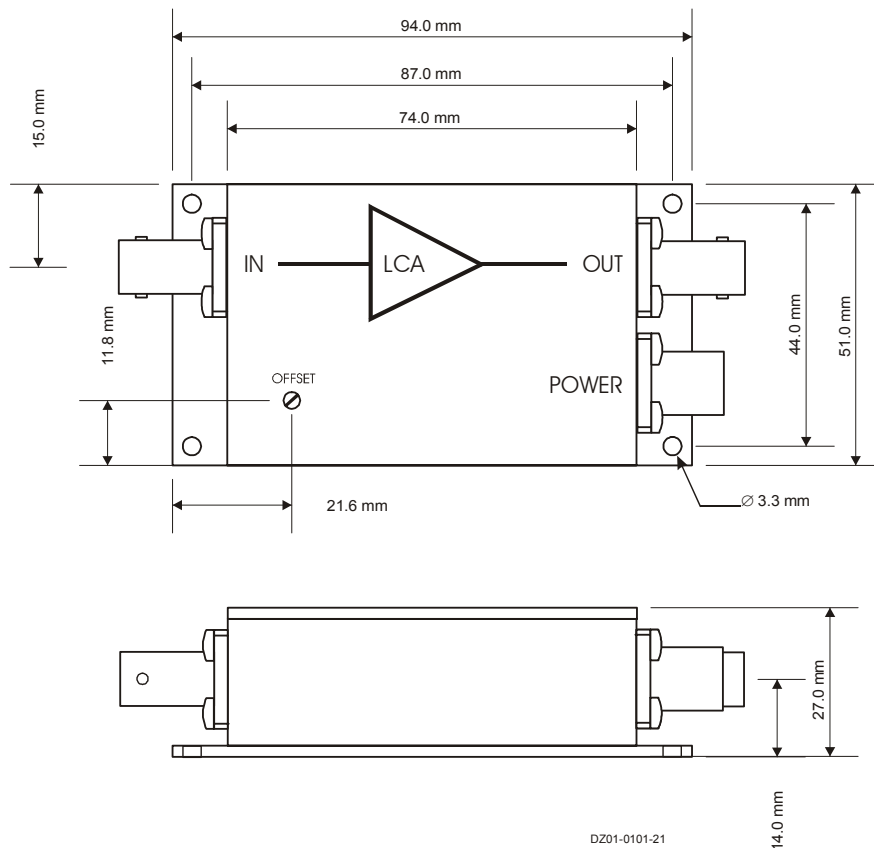


Photo Detector Biasing in Photoconductive Mode:  
Use for Fast Applications and if More Dark Current is Tolerable.  
Bias Voltage Decreases Detector Capacitance.



Ultra-Low-Noise Current Amplifier

Dimensions



DZ01-0101-21

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